

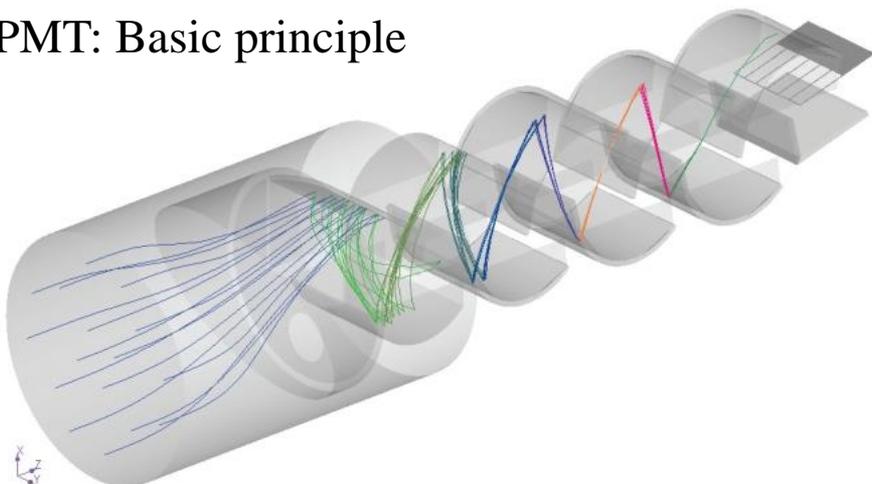
Silicon Photomultiplier (SiPM): a flexible platform
for the development of high-end instrumentation
for nuclear and particle physics

Romualdo Santoro
Università dell'Insubria



Photon detectors: PMT

PMT: Basic principle

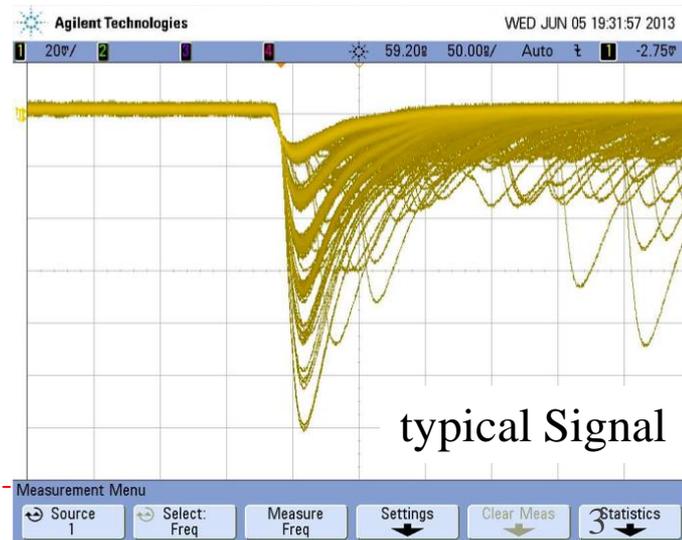
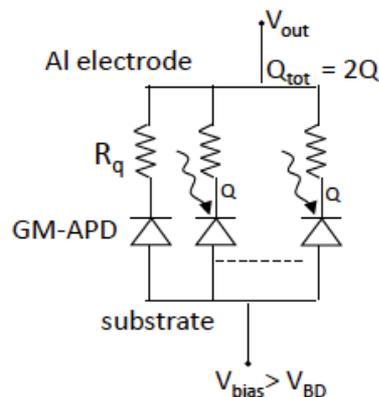
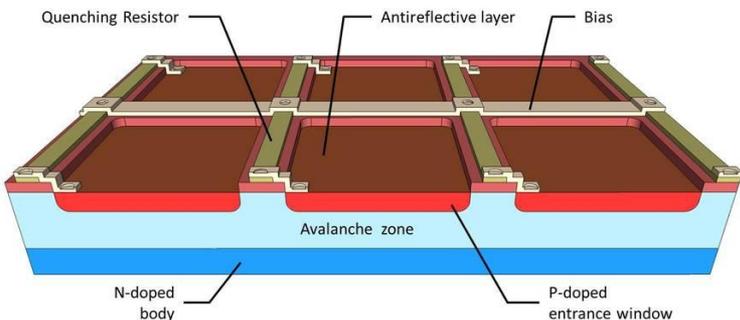


- ▶ Quite mature and robust technology
- ▶ Wide range of products with different characteristics for all the needs
- ▶ A series of parameters to be considered while choosing the proper device
 - ▶ Quantum Efficiency
 - ▶ Photoelectron Collection Efficiency
 - ▶ Gain
 - ▶ Excess Noise Factor
 - ▶ Energy Resolution
- ▶ ... and a well consolidated bibliography form measurements and methods

Photons detectors: SiPM

- ▶ SiPM is a High density (up to $10^4/\text{mm}^2$) matrix of diodes with a common output, working in Geiger-Müller regime
- ▶ Common bias is applied to all cells (few % over breakdown voltage)
- ▶ Each cell has its own quenching resistor (from 100k Ω to several M Ω)
- ▶ When a cell is fired an avalanche starts with a multiplicative factor of about 10^5 - 10^6
- ▶ The output is a fast signal ($t_{\text{rise}} \sim \text{ns}$; $t_{\text{fall}} \sim 50 \text{ ns}$) sum of signals produced by individual cells
- ▶ SiPM works as an analog photon detector: signal proportional to the number of fired cell

SiPM: Basic principle



Why SiPMs are so appealing?

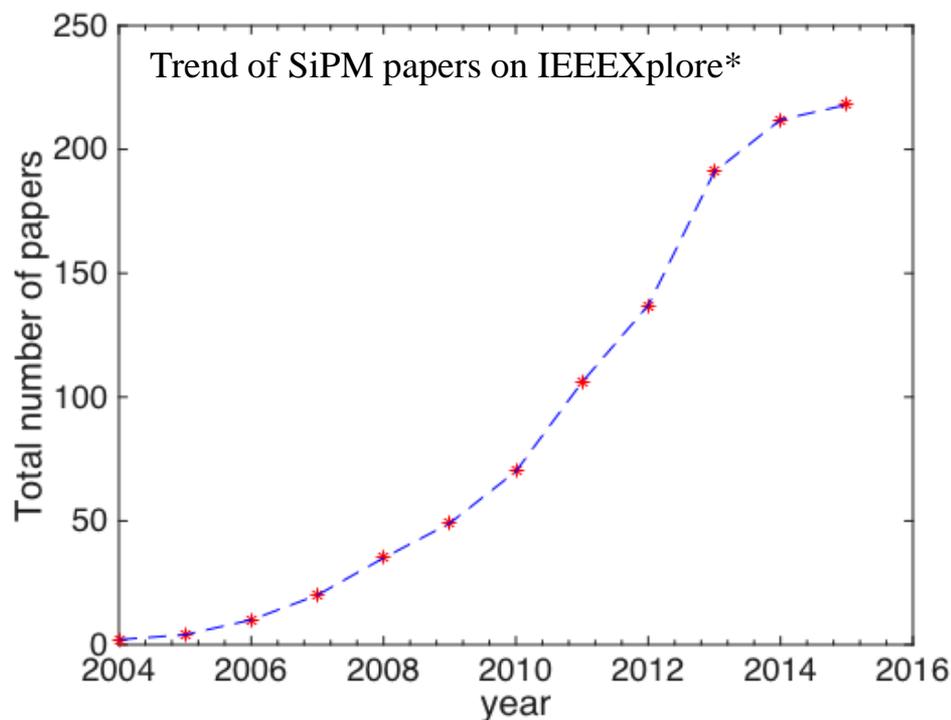
- ▶ High detection efficiency (single photo-electron discrimination)
- ▶ Compact and robust
- ▶ Low operating voltage and power consumption
- ▶ Low cost
- ▶ Withstanding to magnetic field



... and in fact.... they are starting to be widely used in different fields i.e. medical applications, homeland security, spectrometry, high energy physics ...

As of today...

... a clearly growing interest in scientific & industrial communities, where the first is pushing for requirements and characterization methodology while the second for a better technology



* number of papers with “Silicon Photomultiplier” in the abstract or Title, tracked by IEEEXplore

List of producers

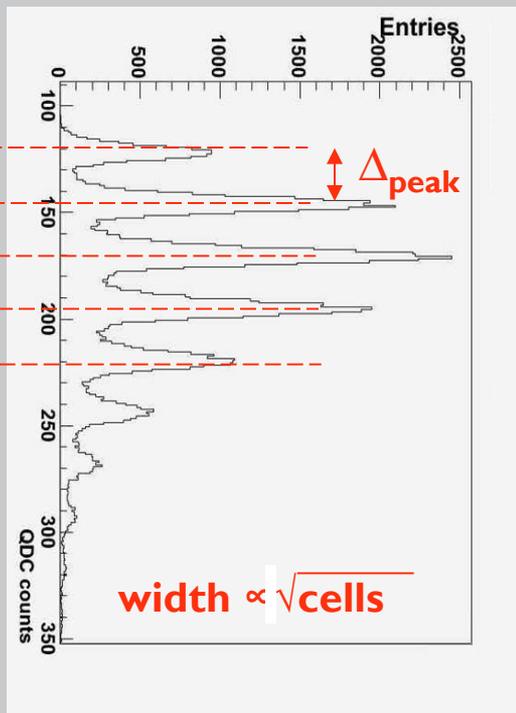
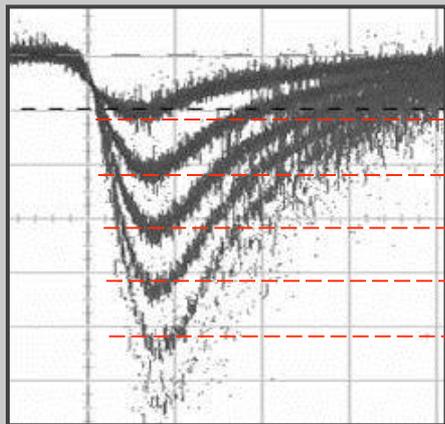
- ▶ AdvanSid
- ▶ CPTA-Advatech
- ▶ CSEM
- ▶ Excelitas
- ▶ E2V
- ▶ Ketek
- ▶ HAMAMATSU
- ▶ PHILIPS Digital Counting
- ▶ PULSAR
- ▶ SENSL
- ▶ STm
- ▶ ZEKOTEK

A typical characterization protocol

- ▶ ***I-V measurements*** (leakage current, quenching resistor, breakdown voltage)
- ▶ ***Noise measurements*** (vs over voltage and vs temperature):
 - ▶ dark counting rate (DCR) vs bias voltage
 - ▶ optical cross-talk (DCR vs threshold)
 - ▶ afterpulse
- ▶ ***Analysis of*** (Poissonian photon) ***spectrum*** (vs temperature)
 - ▶ resolution power (how many photons can I distinguish?) & gain
 - ▶ working point optimization (at low and large flux)
 - ▶ noise measurement (not DCR; essentially system noise and cell-to-cell variations)
 - ▶ optical cross-talk (deviations from the Poissonian distribution)
- ▶ ***linearity & dynamic range***
- ▶ ***Spectral response*** (PDE vs λ , PDE vs temperature)
- ▶ ***timing properties*** and time resolution (currently $O(100\text{ps})$)

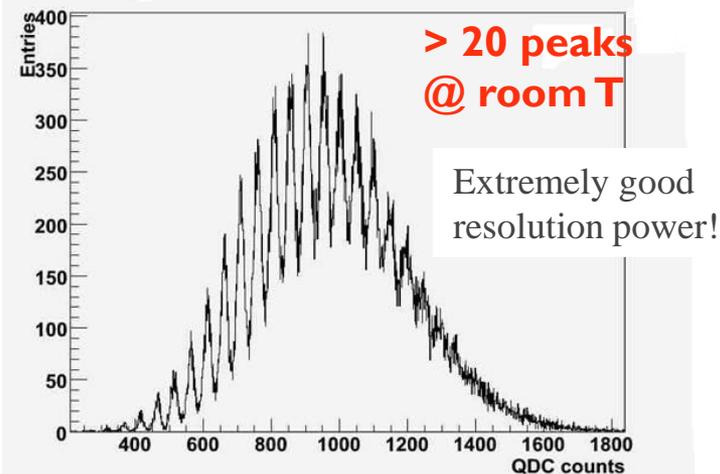
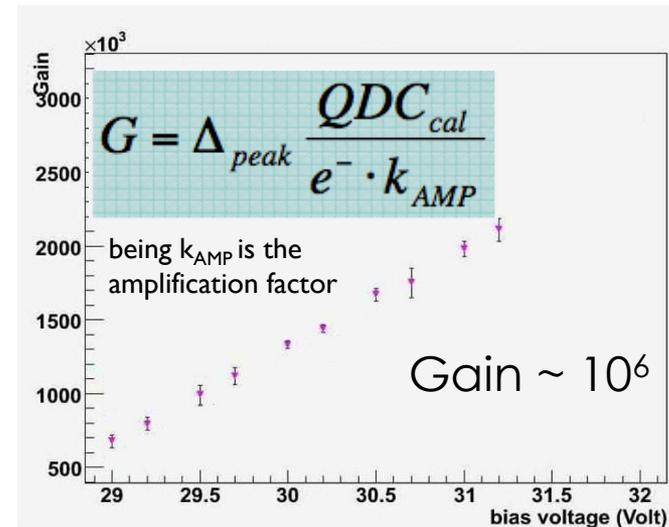
Photon Spectrum & Gain

Light source: CAEN ultra-fast LED (SP5601) OR Pico Quant PDL 800 - light at ~ 510 nm (green)



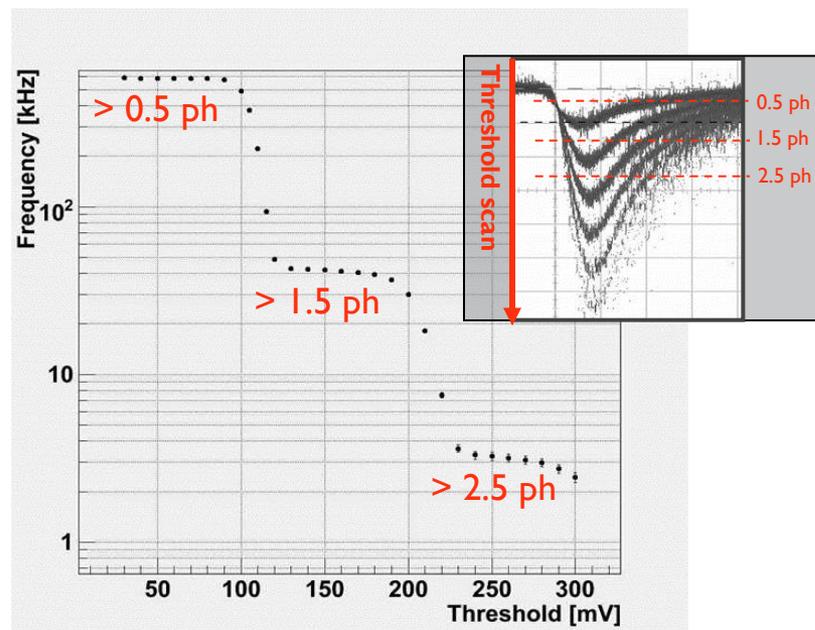
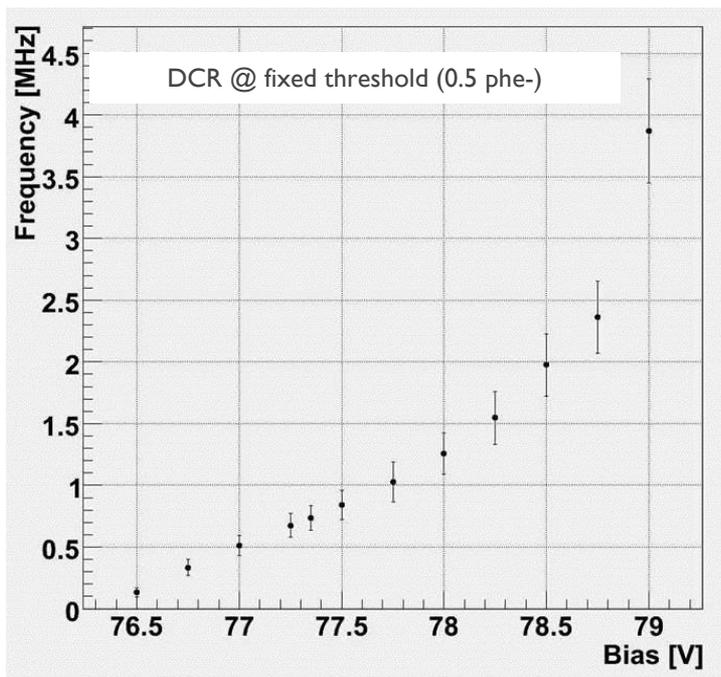
○ Peak width:

- System noise
- Cell-to-cell gain variation (process uncertainties)
- I_{leak} fluctuations
- Spurious hits in the QDC integration time



Dark Count Rate & Xtalk

The **D**ark **C**ounts (DCR) measure the rate at which a Geiger avalanche is randomly initiated by thermal emission.

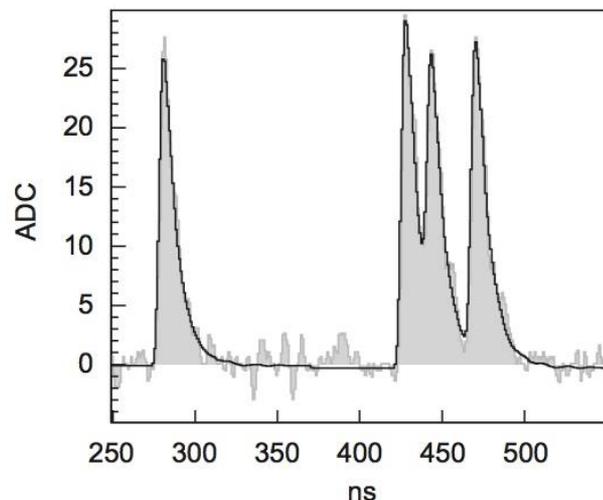


an avalanche generation can fire another cell with a photon; measuring the DCR for different thresholds is possible to define and evaluate the **Optical Cross talk** as:

$$X_{talk} = \frac{DCR(1.5 ph)}{DCR(0.5 ph)}$$

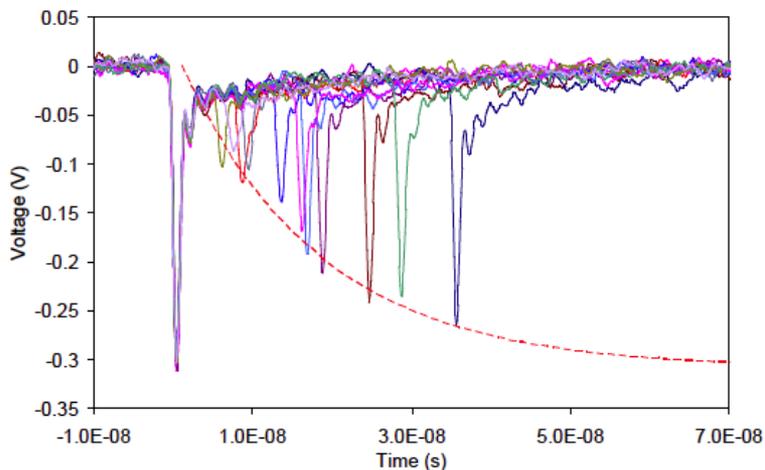
After Pulse

It is a delayed avalanches triggered by the release of a charge carrier that has been produced in the original avalanche and has been trapped on an impurity



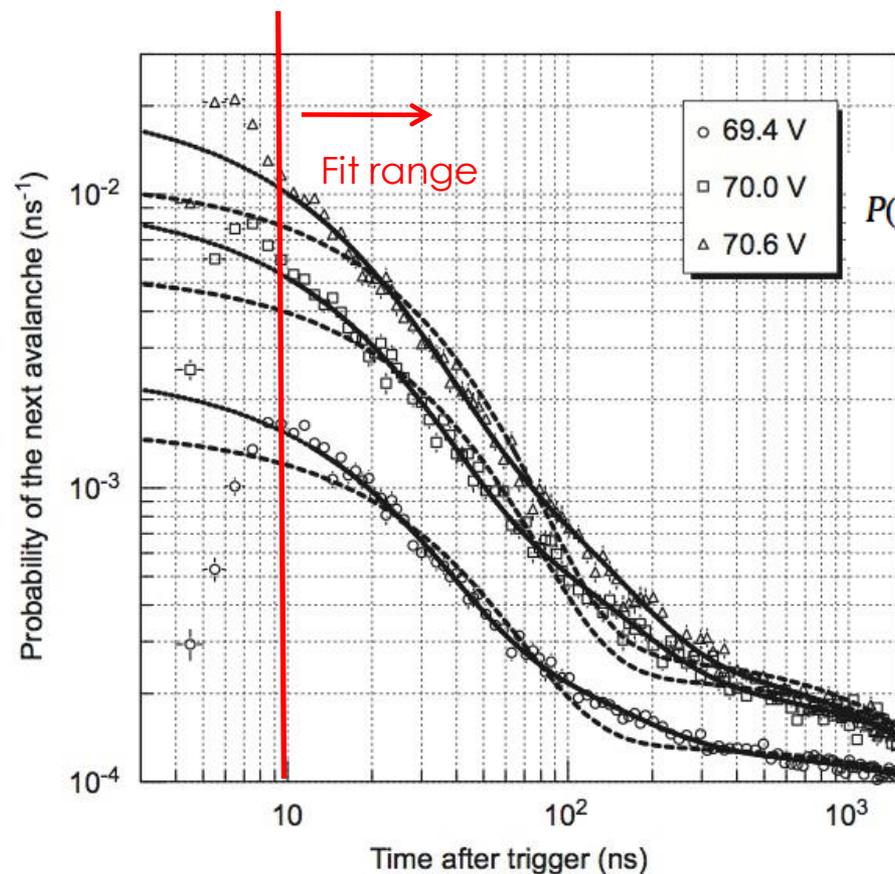
Output of a HAMA MPPC 11-50, digitized by a CAEN V1729 waveform digitizer, as reported by Y. Du, F. Retiere (NIM A 596 (2008) 396–401)

A quantification of the effect essentially proceeds through an analysis of the pulses time structure, expected to be Poissonian without the after pulse phenomenon:



After Pulses measured on the same pixel v.s. time
The exponential recovery time is clearly shown (C.Piemonte)

After Pulse



What is plotted on the Y axis is:

$$P(t) = \int_0^t [1 - P_{AP}(x)] dx P_{DN}(t) + \int_0^t [1 - P_{DN}(x)] \times dx P_{AP}(t).$$

Where:

$$P_{AP}(t) = \sum_{i=1}^{\infty} \frac{\lambda^i}{i!} e^{-\lambda} \frac{i}{\tau} e^{-t \cdot i / \tau}$$

$$P_{DN}(t) = R e^{-Rt}$$

Are the After Pulse and Dark Noise probabilities

Fig. 4. Timing distribution of the first pulse following the trigger. The dotted lines are fits with a single after-pulsing time constant, while the solid lines included two time constants. The dashed lines show the two exponential function behaviors beyond the fit range.

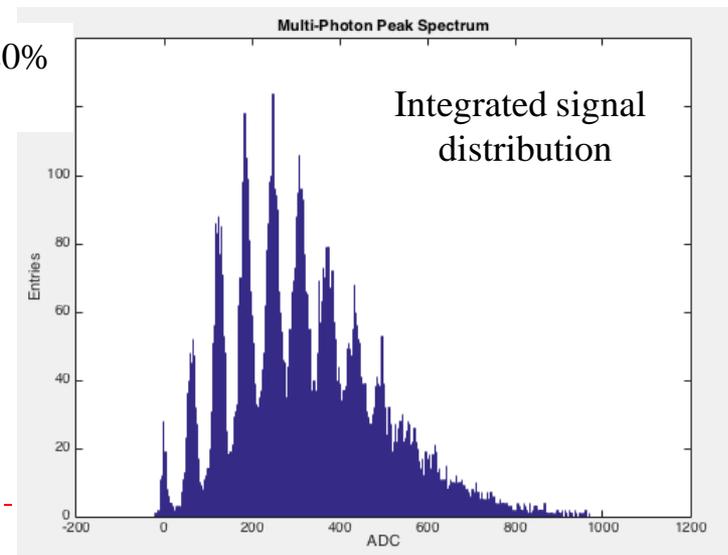
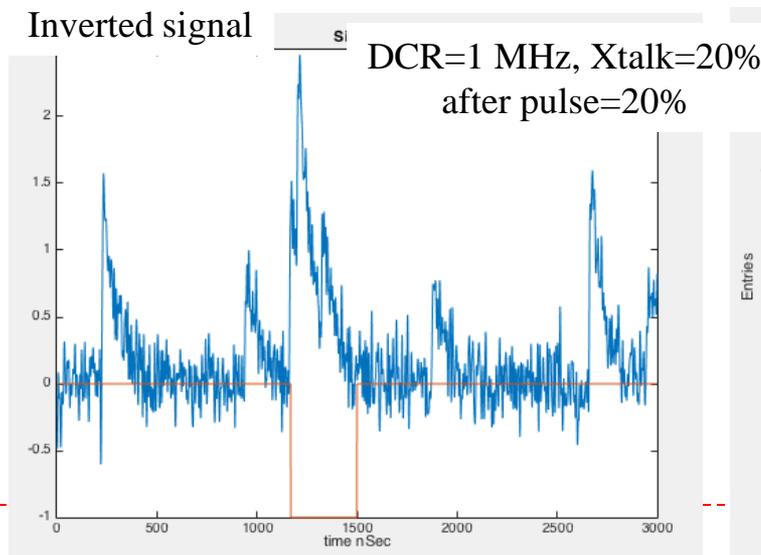
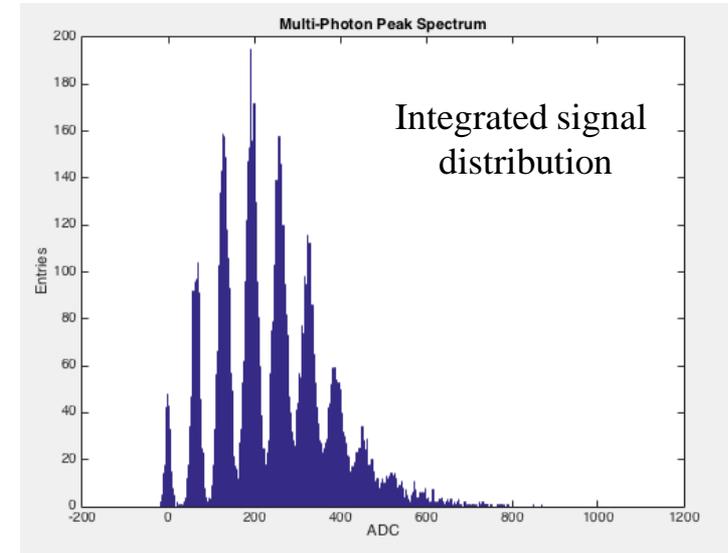
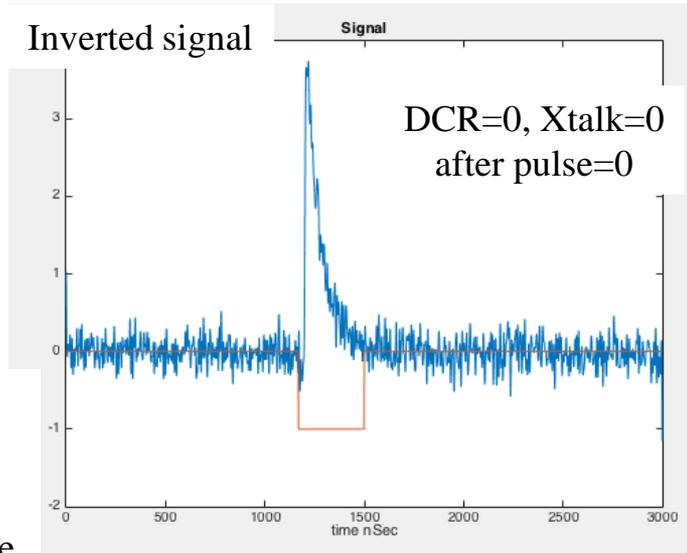
Y. Du, F. Retiere (NIM A 596 (2008) 396–401)

Simulated Signal

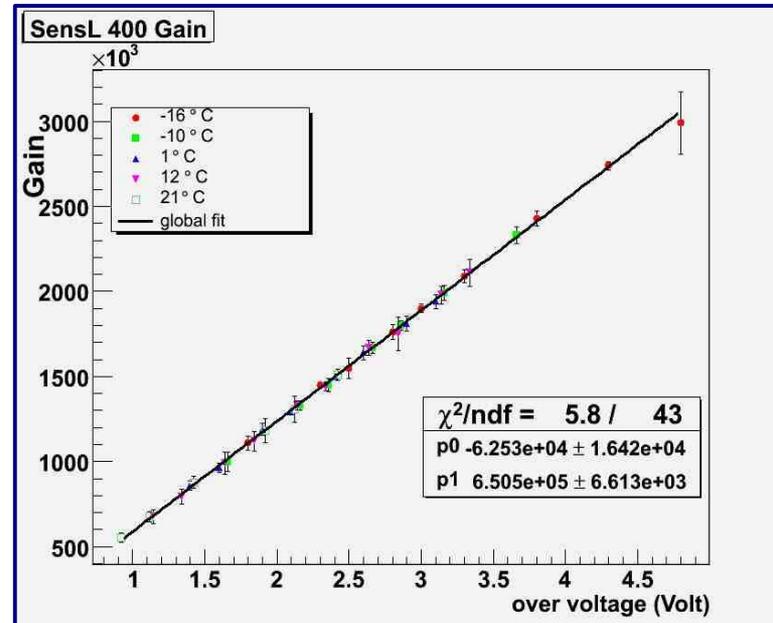
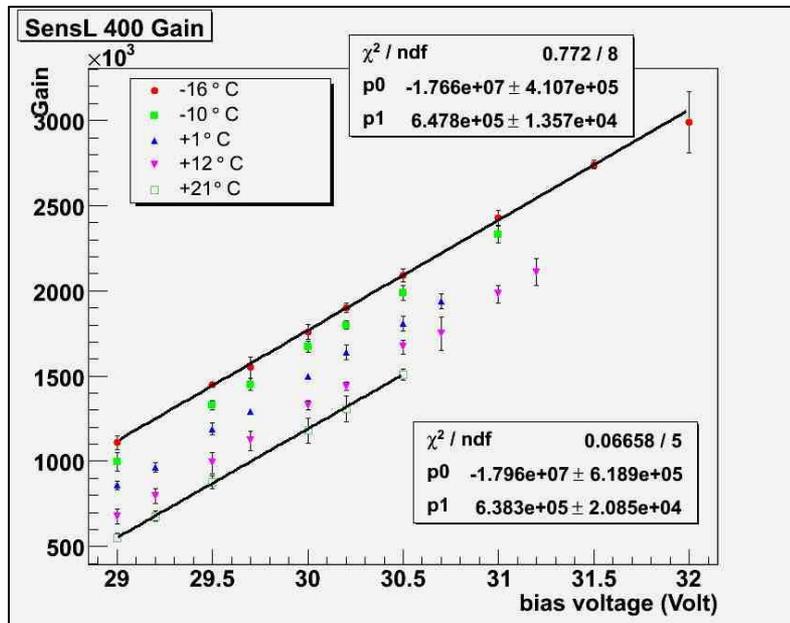


Toy settings:

- ▶ SNR=10
- ▶ Tau=70nSec
- ▶ CellToCell = 0.1 phe
- ▶ sampling 1 nSec
- ▶ gate =320nSec



Gain temperature variations

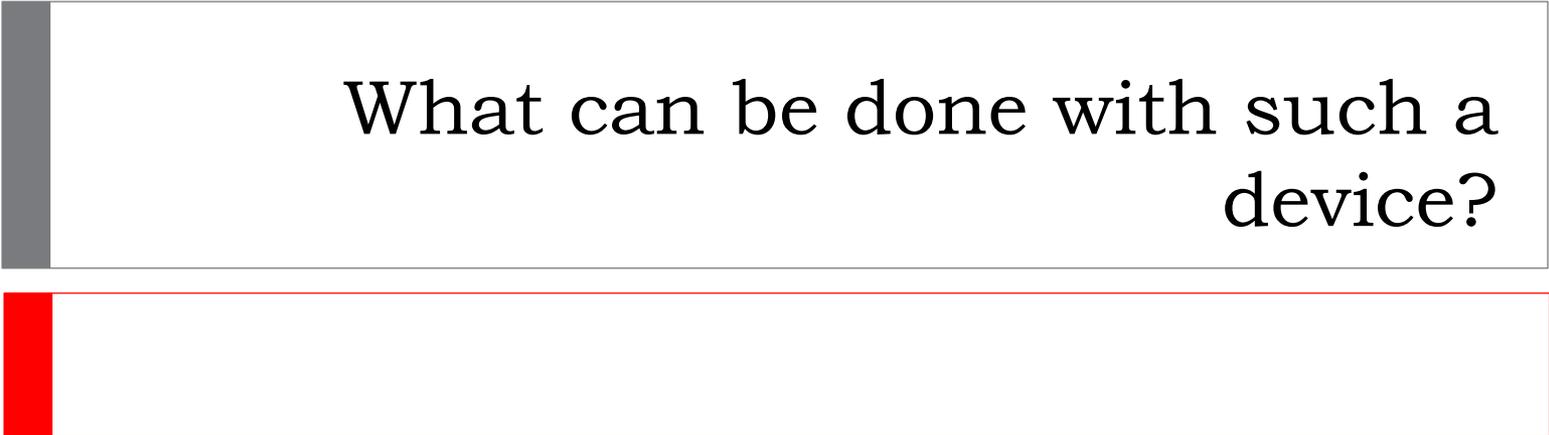


$$\frac{dV}{dT} = - \frac{dG}{dT} \frac{1}{\frac{dG}{dV}}$$

$$V_{BD} = \frac{dV}{dT} (T - T_{RT}) + V_{RT}$$

Breakdown Voltage rescaled
accounting for temperature variation

M. Ramilli: IEEE NSS Conf. (2008), pp. 2467



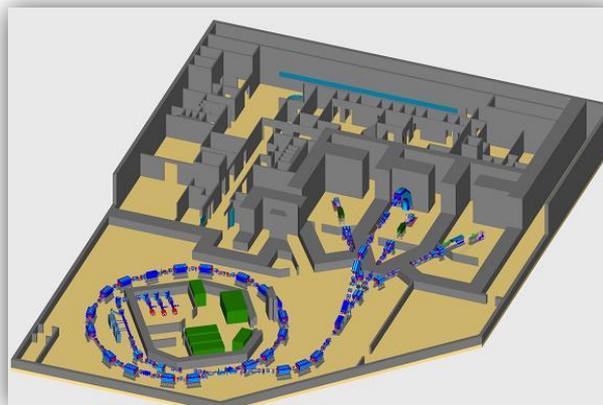
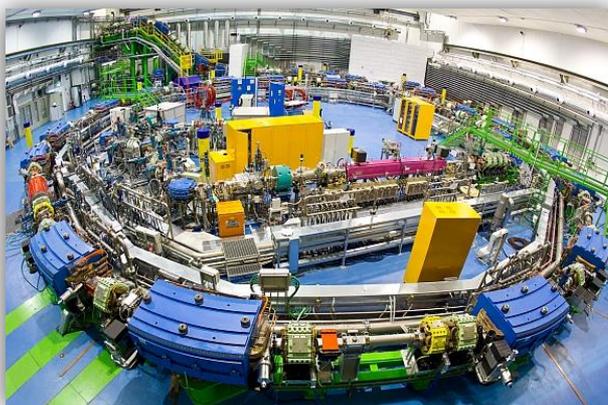
What can be done with such a device?

A slide with a white background. The text "What can be done with such a device?" is centered in a black serif font. To the left of the text is a vertical grey bar. Below the text is a horizontal red box with a thin red border, which is currently empty.

Beam profile at CNAO

fondazione CNAO
Centro Nazionale di Adroterapia Oncologica per il trattamento dei tumori

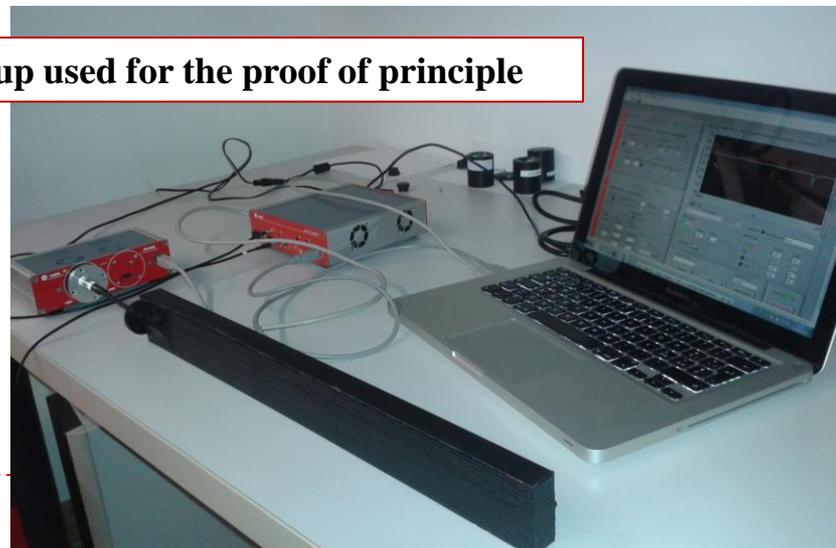
- ▶ Protons (250MeV) and carbon ions (4.8 GeV) beam
- ▶ Three treatments rooms



Measurement of the beam profile: wide dynamic range (≈ 4 order of magnitude)

- ▶ Scintillating fiber (d=1mm)
- ▶ SiPM (1x1mm²)
- ▶ 1st stage amplification
- ▶ Digitizer for signal integration

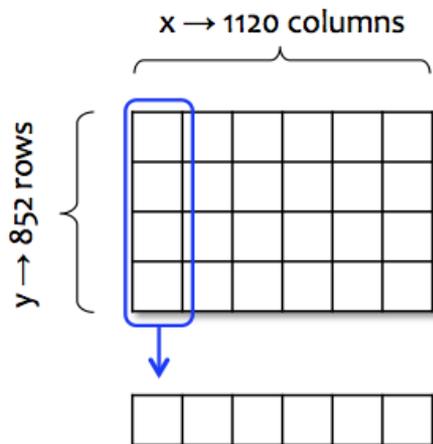
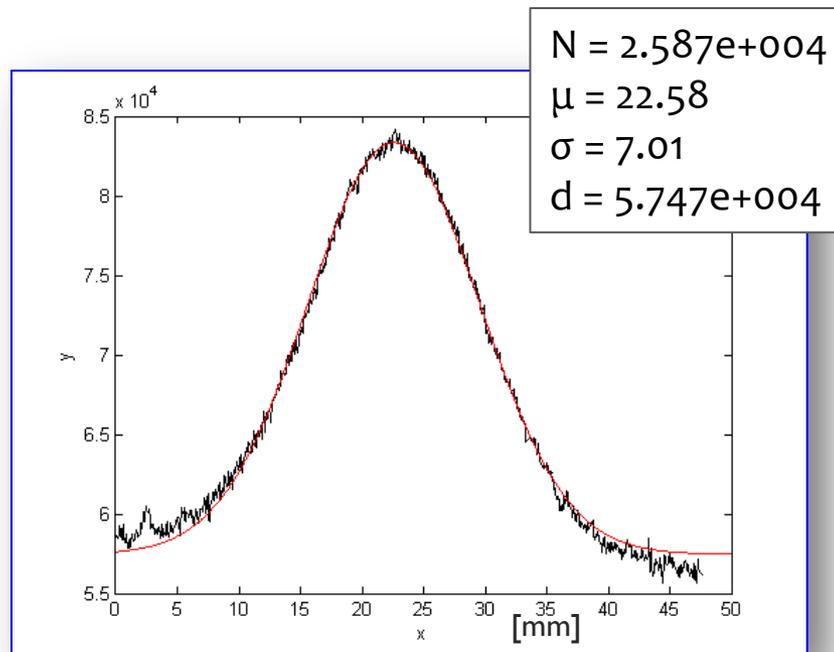
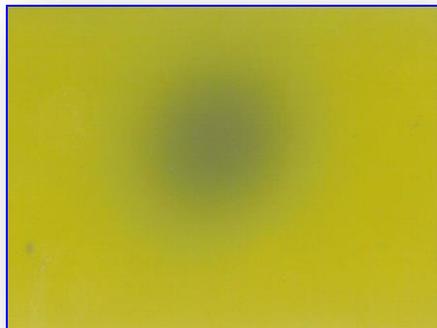
Setup used for the proof of principle



Beam Image

- ▶ Proton beam @ 117 MeV
- ▶ Intensity $\approx 2 \cdot 10^8$ / spill (1 sec long)
- ▶ duty cycle = 20%

Film image digitized



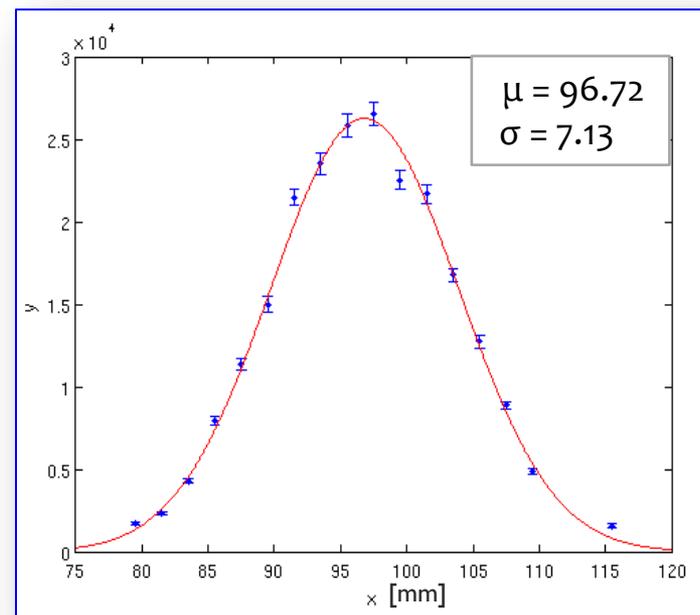
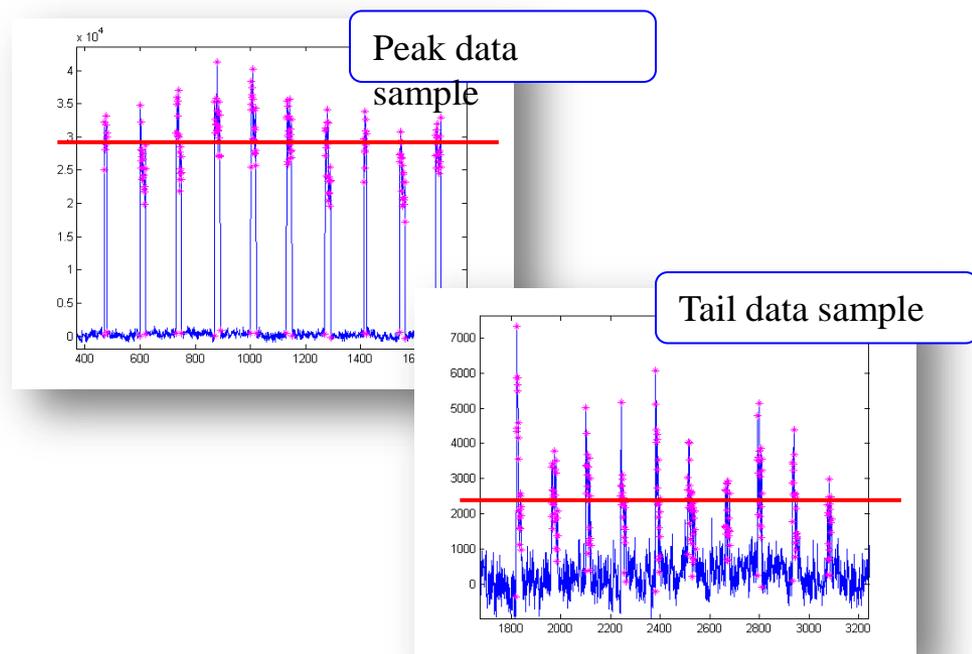
Horizontal projection of the red component

- ▶ Profile is estimated as the sum along the y (To be compared with the SiPM method)
- ▶ The fit is done with gauss + const

Beam profile: integration mode

The procedure

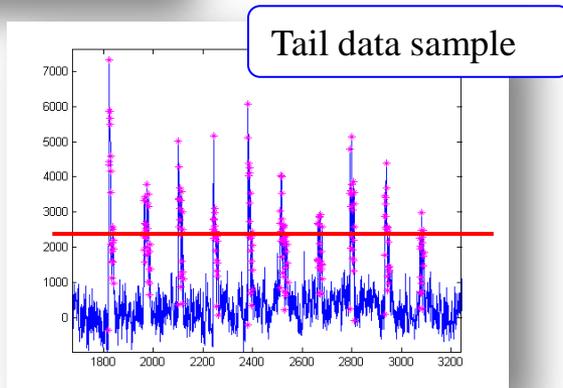
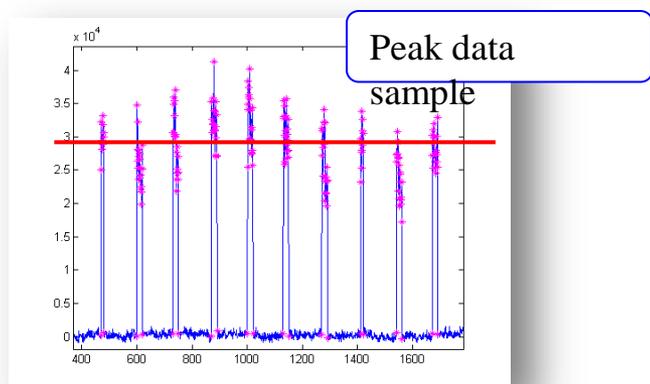
- ▶ Baseline estimation: mean and std with the first 300 points
- ▶ Baseline subtraction + smoothing (3 points moving average)
- ▶ Identify the first and last point for each peak
- ▶ The mean value in all the spills is used for the beam profile



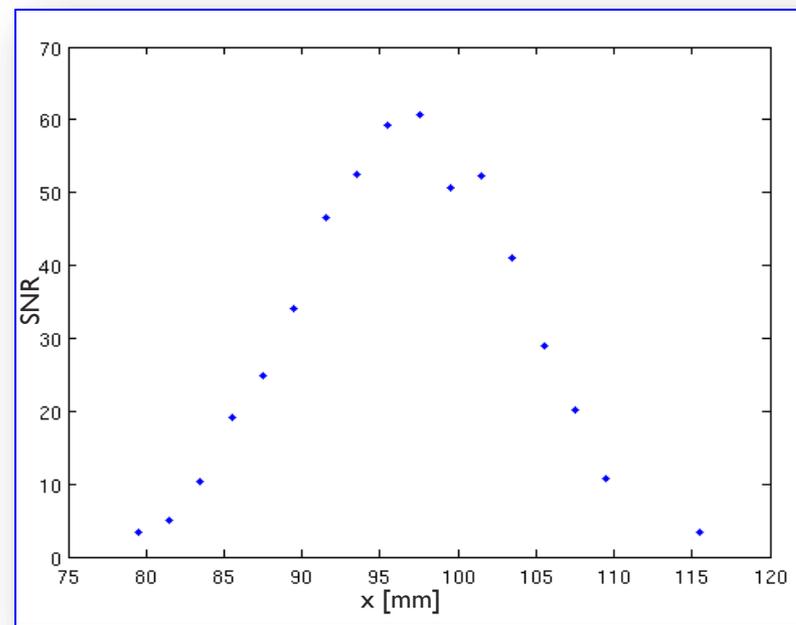
Beam profile: integration mode

Sensitivity

- ▶ Beam profile in SNR unit: from 3 (tail) to 60 (peak)



Mean of every value above threshold
 σ background

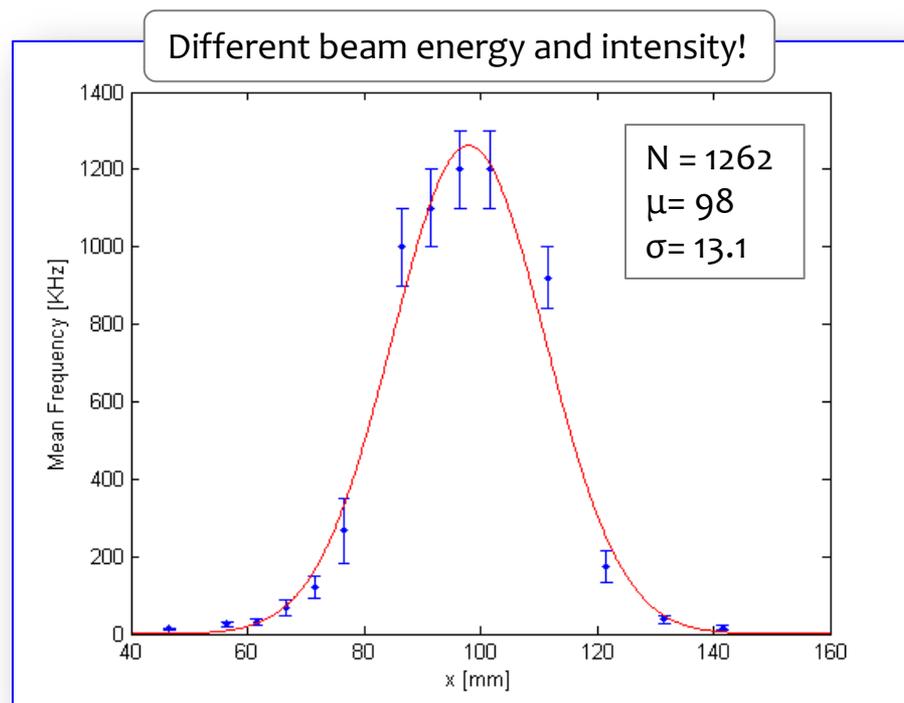


Beam profile: counting mode

The procedure

- ▶ Leading-edge discriminations with ad-hoc threshold
 - ▶ Dark count at Hz level
- ▶ Mean value and standard deviation over different points in the spill

Position [mm]	Mean Frequency [KHz]	Std Frequency [KHz]
46,54	12,7	2,1
56,54	25	7,7
61,54	29,4	8,7
66,54	67,9	21,4
71,54	121	27,4
76,54	266,3	84,6
86,54	1000	100
91,53	1100	100
96,52	1200	100
101,52	1200	100
111,54	919,6	79,9
121,54	174,6	40,7
131,54	37,9	10,4
141,55	16,1	4,4



we get the 4 orders of magnitude

Development of Intra-operative Beta Probes

- N. Hudin, NDIP 2011
- F Bogalhas et al., Phys. Med. Biol. 54 (2009) 4439–4453

The precise localization and complete surgical excision of tumors are one of the most important procedures in the treatment of cancer. In that context, the goal is to develop new intra-operative probes to help surgeons to detect malignant tissues previously labeled with beta-emitting radiotracers.

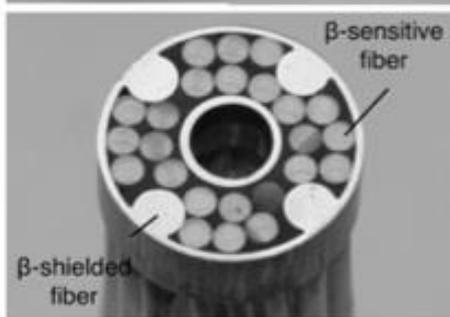


A first prototype was designed and constructed using multi-anode PMT; now, the use of SiPM is being pioneered.



the MA-PMT based probe

Exchangeable detection head (10 and 24 fibers)



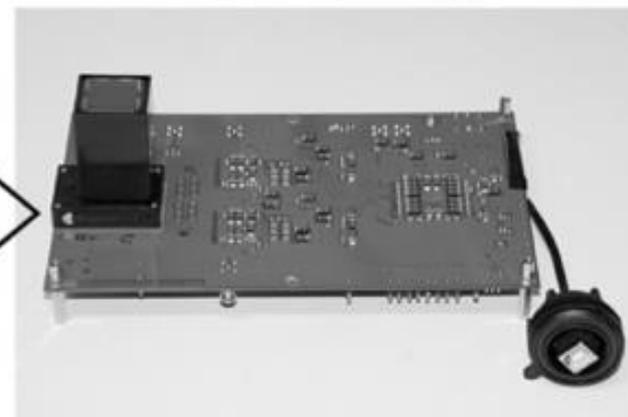
1.5 mm ϕ detection elements

Optical light guide



28 x 1 mm ϕ x 2 m long optical fibers

MC-PMT/electronic read-out assembly



Hamamatsu H7546B MC-PMT
2 X 32-channels ASIC
Electronic ADC board

Main result on the MA-PMT based probe

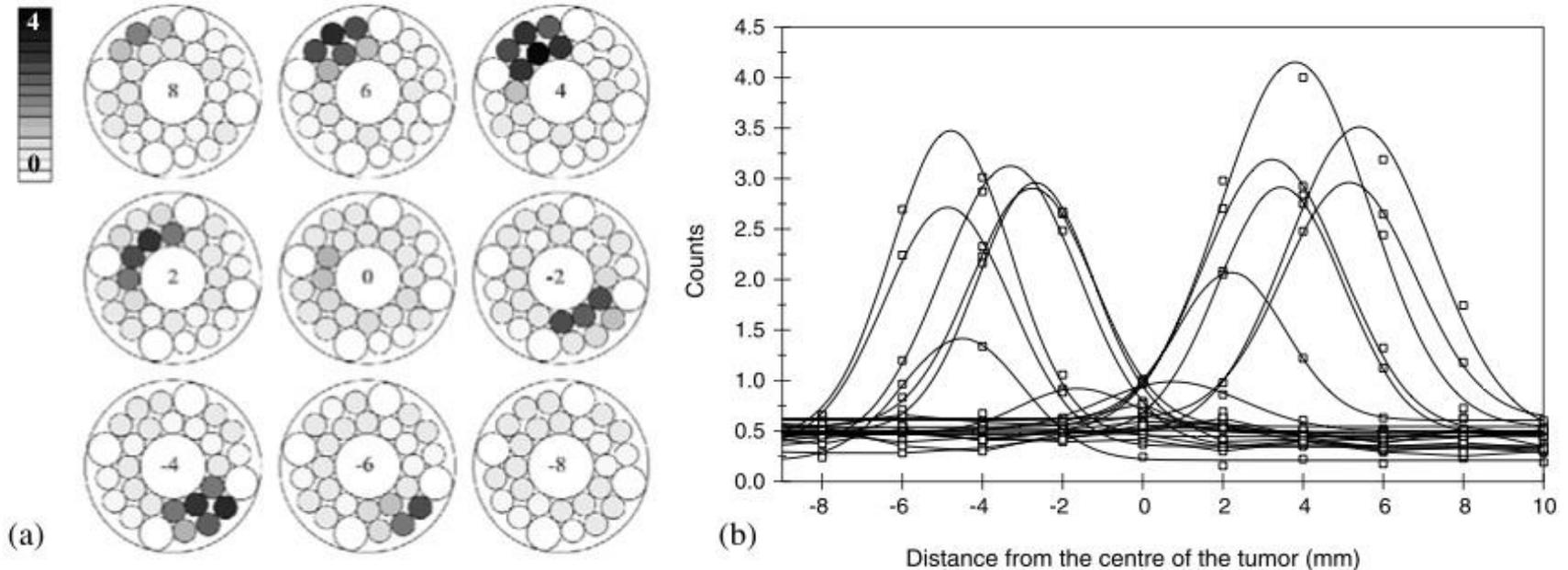
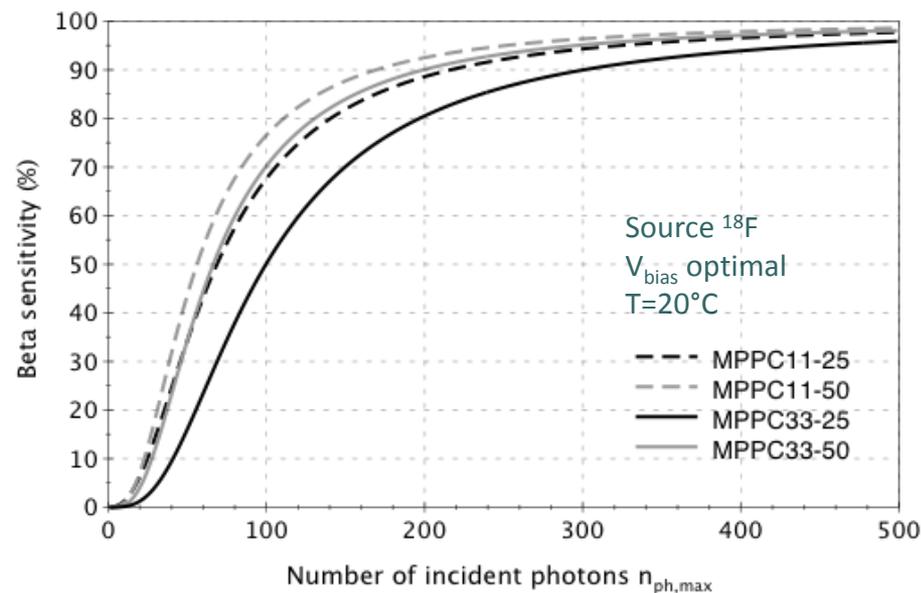
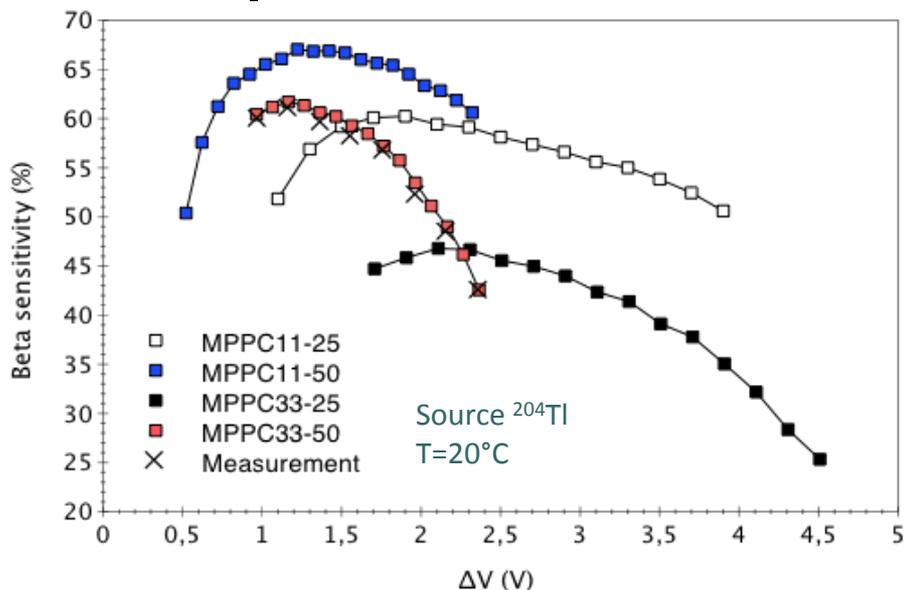


Figure 6. Image sequence (a) and count profiles (b) measured as the probe (large detection head) was used in 2 mm scanning steps over the 5 mm diameter tumour disc (an uptake ratio of 8:1).

The radiotracer concentration in the brain phantom and the normal region was set to 34 kBq ml^{-1} and the concentration in the tumour discs was scaled to achieve the corresponding uptake ratio (58.5 kBq ml^{-1} , 106 kBq ml^{-1} , and 280 kBq ml^{-1}).

Preliminary result of a fiber+SiPM (MMPC) based element



- Very good agreement between the measured and modeled beta sensitivity
- Optimal ΔV depends on the features of the SiPM device but is independent on T and $n_{\text{ph,max}}$
- The sensitivity drops as the Over-voltage increases since the thresholds to keep the noise constant has to be raised (noise level 1 Hz!)

- Minimal $n_{\text{ph,max}}$ value to reach a beta sensitivity of 90% ranges from 170 for different sensors
- MPPC33-50 appears as the best compromise between sensitivity and light collection efficiency

SiPM for homeland security



- ▶ MODES_SNM has been founded by the European Commission within the Framework Program 7
- ▶ The Main Goal is the development of a system with detection capabilities of “difficult to detect radioactive sources and special nuclear materials”
 - ▶ Neutron detection with high γ rejection power
 - ▶ γ -rays spectrometry
- ▶ Other requirements
 - ▶ Mobile system
 - ▶ Scalability and flexibility to match a specific monitoring scenario
 - ▶ Remote control, to be used in covert operations

modes SNM

Modular Detector System for Special Nuclear Material



Two main Goals

- ▶ The demonstrator: a fully integrated system based on high pressure scintillating gas readout by PMT
 - ▶ Fast neutron (^4He)
 - ▶ Thermal neutron (^4He with Li converter)
 - ▶ Gamma (Xe)
- ▶ The proof of principle of PMT replacement with the innovative SiPM



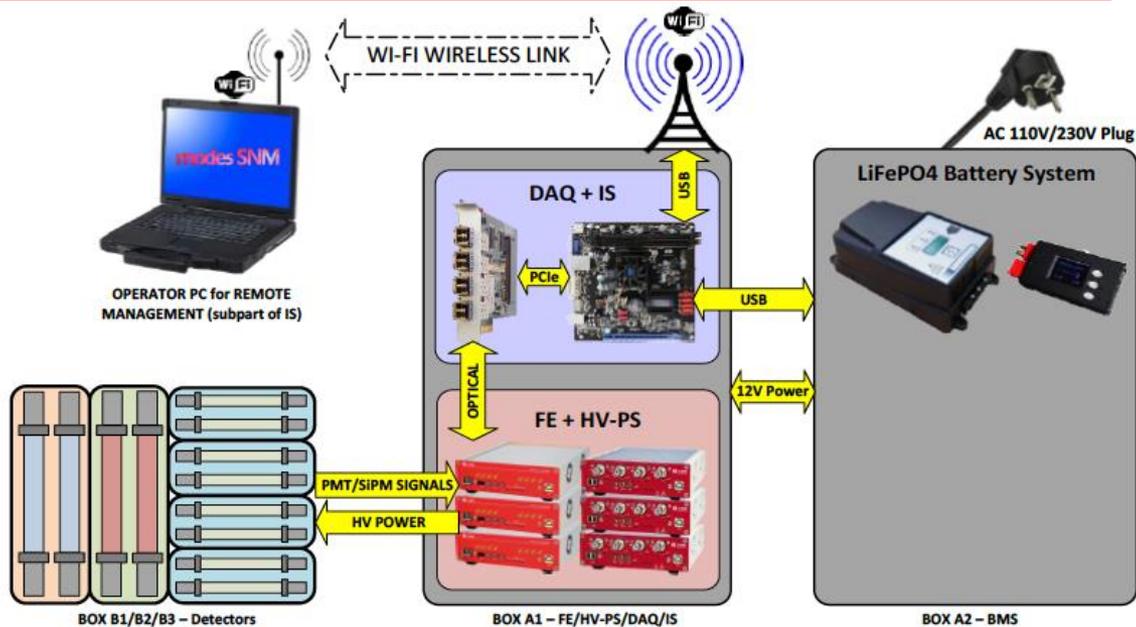
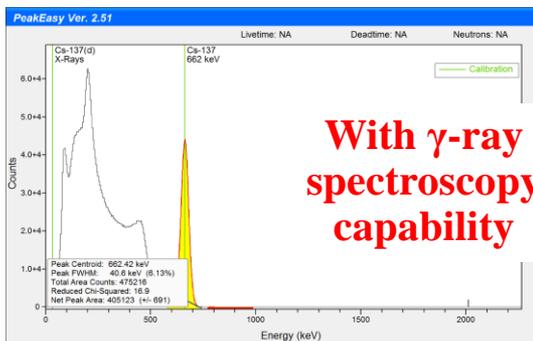
Available on the market:

<http://www.arktis-detectors.com/products/security-solutions/>



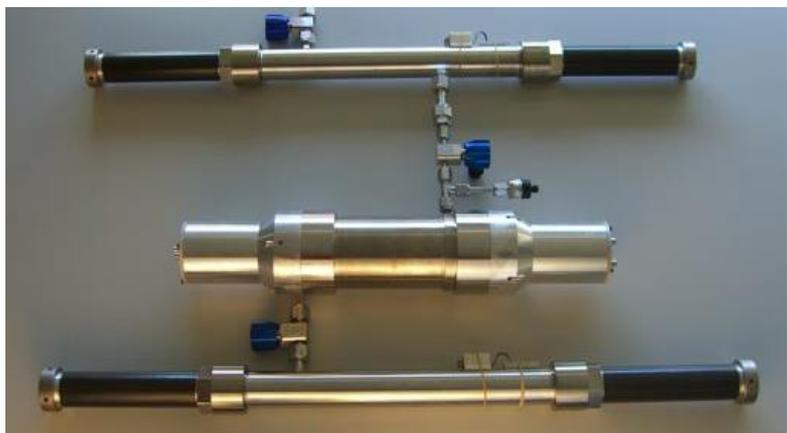
Now prototyped by Arktis and shown at NSS/MIC 2014 at Seattle

MODES_SNM System overview



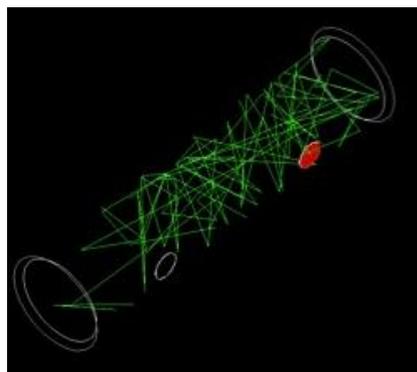
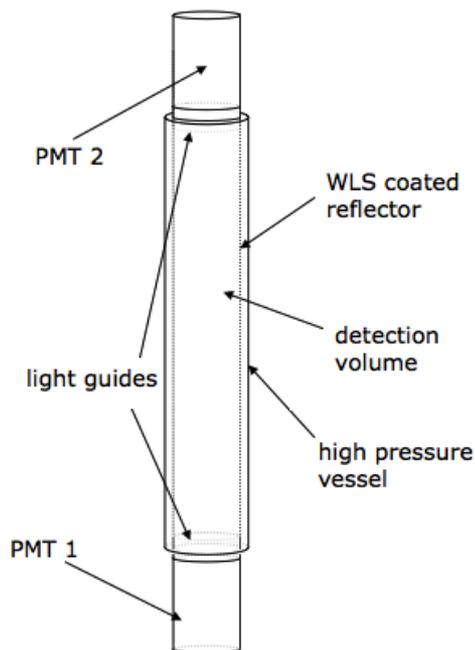
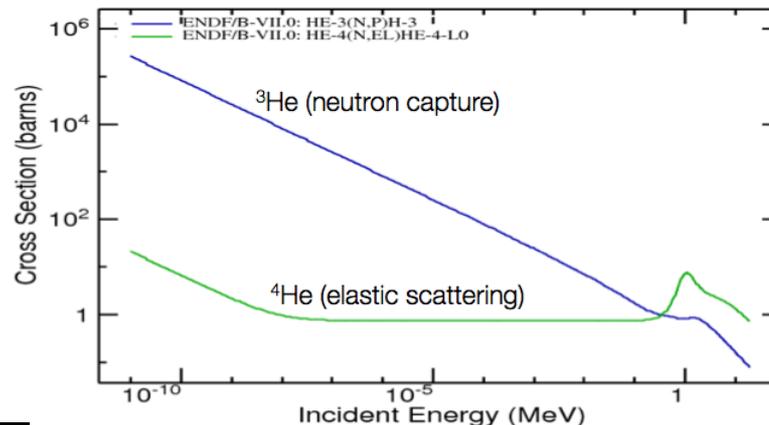
Modular system optimized for:

- ▶ Fast neutron (^4He)
- ▶ Thermal neutron (^4He with Li converter)
- ▶ Gamma (Xe)



Baseline technology

- ▶ The Arktis technologies is based on high pressurized ^4He for the neutrons detection
- ▶ The main key features of ^4He
 - ▶ Reasonably high cross section for n elastic scattering
 - ▶ Good scintillating properties
 - ▶ Two component decays, with τ at the ns and μs levels
 - ▶ Cheaper and easier to be procured wrt ^3He

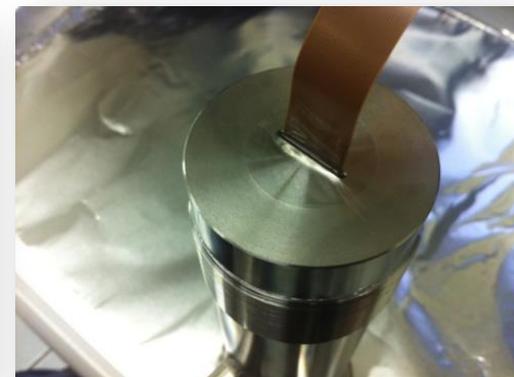
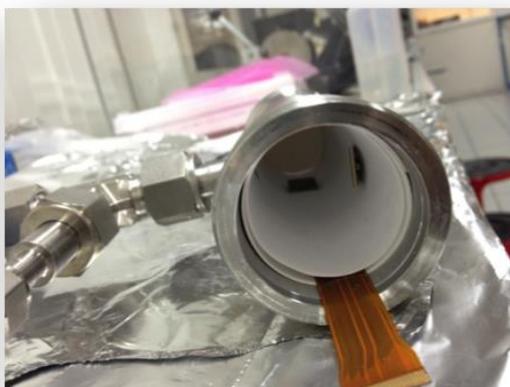
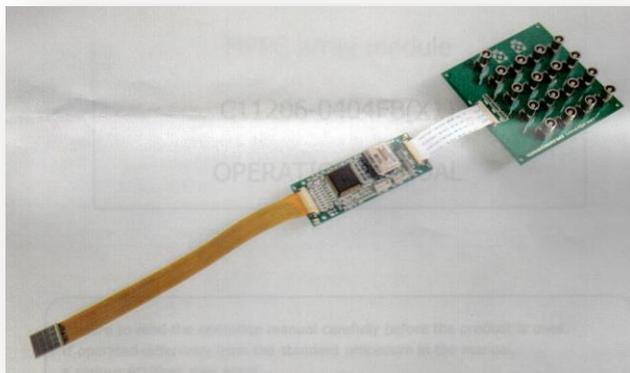


	Z	Photons/MeV	Peak emission
^4He	2	15'000	70 nm
^{40}Ar	18	40'000	128 nm
^{131}Xe	54	46'000	175 nm
Nal(Tl)	11,53	40'000	415 nm

- ▶ 44 cm diameter x 47 cm sensitive length
- ▶ 180 bar ^4He sealed system maintaining gas purity

R. Chandra et al., 2012 JINST 7 C03035

SiPM and the proof of principle



- ▶ A short tube (19 cm) used for the proof of principle
- ▶ Filled with ^4He at 140 bar, an integrated wavelength shifter and two SiPMs mounted along the wall (by ARKTIS)
- ▶ Two SiPMs read-out through the Hamamatsu electronic board (C11206-0404FB)
- ▶ 2-channels 3-stage amplification with leading edge discrimination (SP5600A – CAEN)
- ▶ Digitizer with a sampling rate of 250 Ms/s 12 bit digitization (V720 – CAEN)



Counting measurements

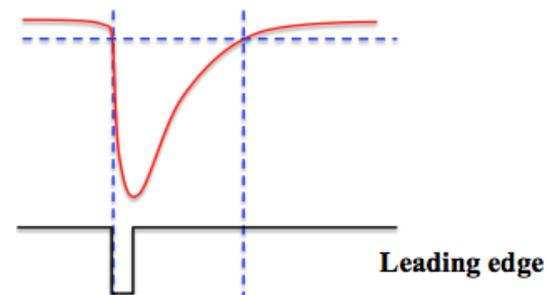
Test performed measuring:

- ▶ Background, n and γ counting rate using ^{252}Cf and ^{60}Co source in contact

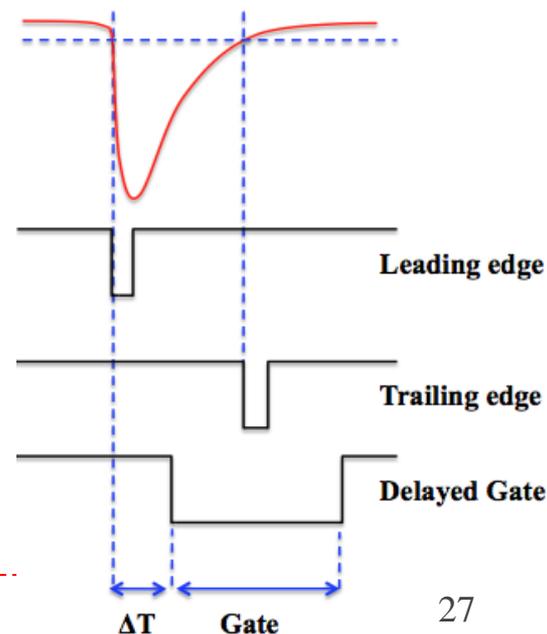
Two triggering scheme:

- ▶ Trailing edge discrimination in coincidence
- ▶ Trailing edge and delayed gate of each single SiPM in coincidence
 - ▶ Few parameters to be optimized:
 - ▶ Leading and trailing threshold
 - ▶ Delay time (ΔT)
 - ▶ Gate aperture

1st Trigger Scheme



2nd Trigger Scheme



SiPM counting measurements



Result for the different trigger scheme @ 28°C

Counting rate [Hz]	no source	^{60}Co in contact	^{252}Cf in contact
Leading edge discrimination (Ch0 n Ch1) @31mV [Hz]	0.05	1.32	10.18
Delayed trigger, single detector [delay 700 ns, long gate 2 μs]	0.02	0.05	12.27
Delayed trigger, Ch0 n Ch1	0.01	0.01	8.61

An amazing result, corresponding to a γ rejection power at the 10^6 level

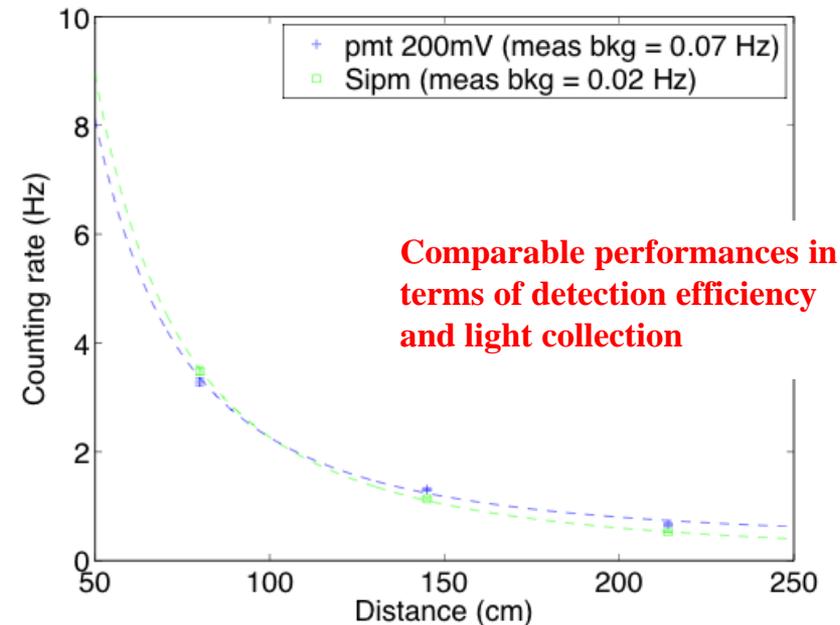
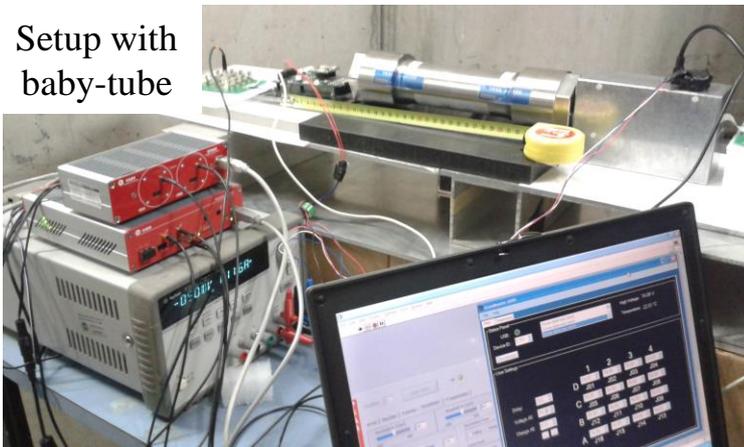


[10 counts in 1000s, for a number of γ given by acceptance*activity*time
 $= 1/3 * 3 * 10^4 * 10^3 \sim 10^7$]

SiPM VS PMT counting measurements

- ▶ Trigger: pulse-height discrimination and coincidence among the 2 channels in the tube
 - ▶ Threshold set to have low bkg counting rate
 - ▶ No γ -rejection algorithm
 - ▶ Same strategy for both tubes
- ▶ The counting rate was measured at different distances from the ^{252}Cf source

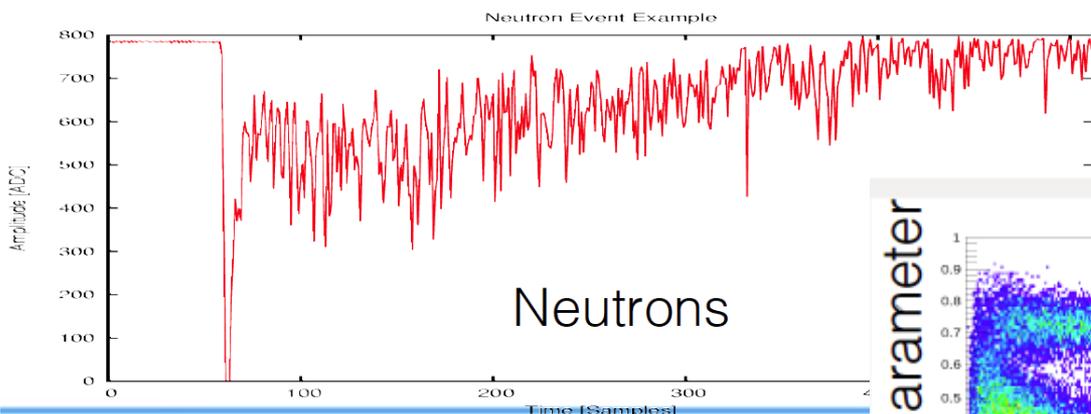
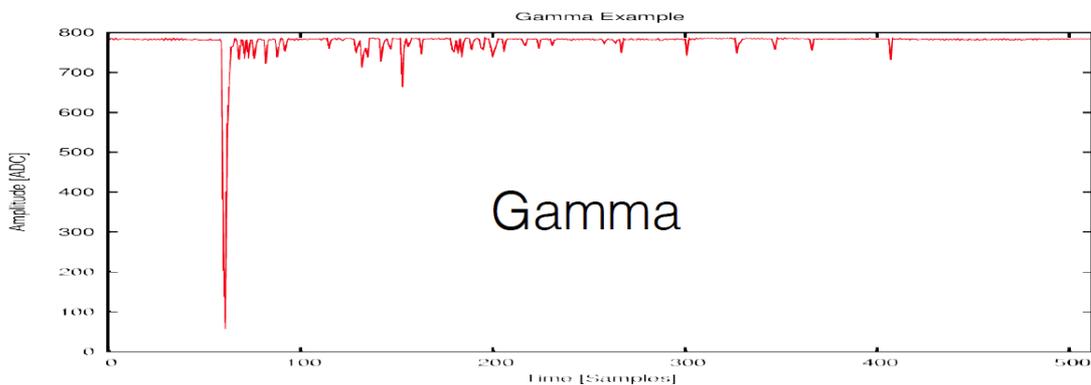
Setup with baby-tube



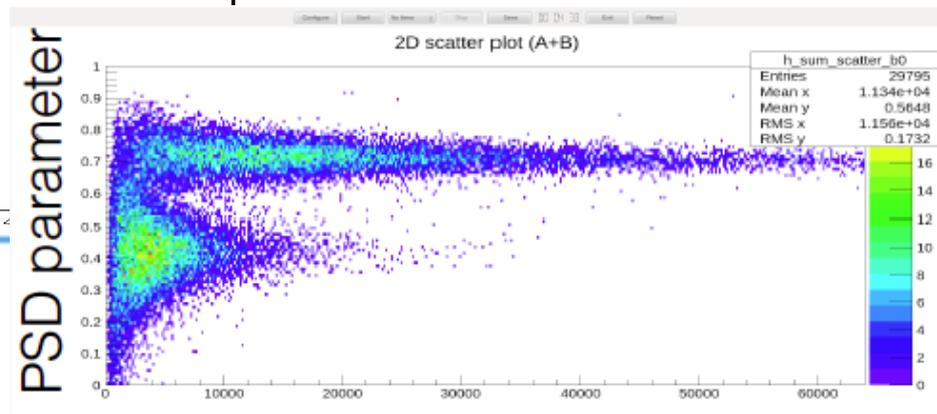
Spares



Neutron/ γ separation



$$PSD = (Q_{total} - Q_{short}) / Q_{total}$$

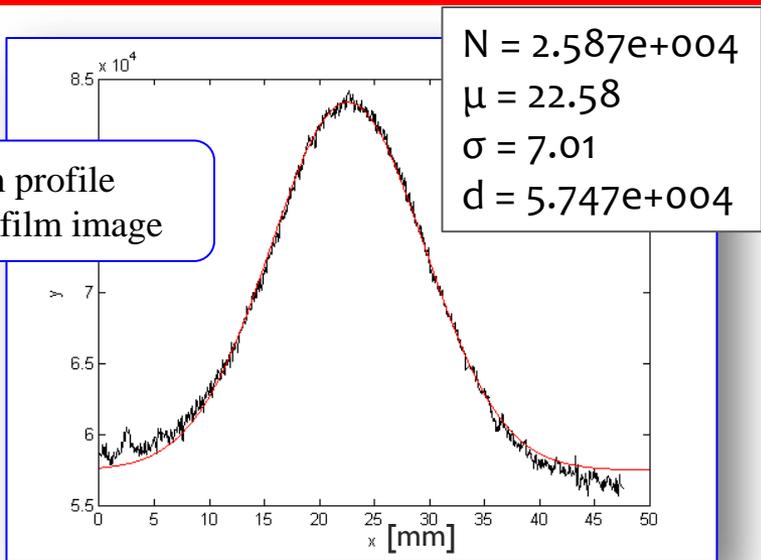


Decision tree

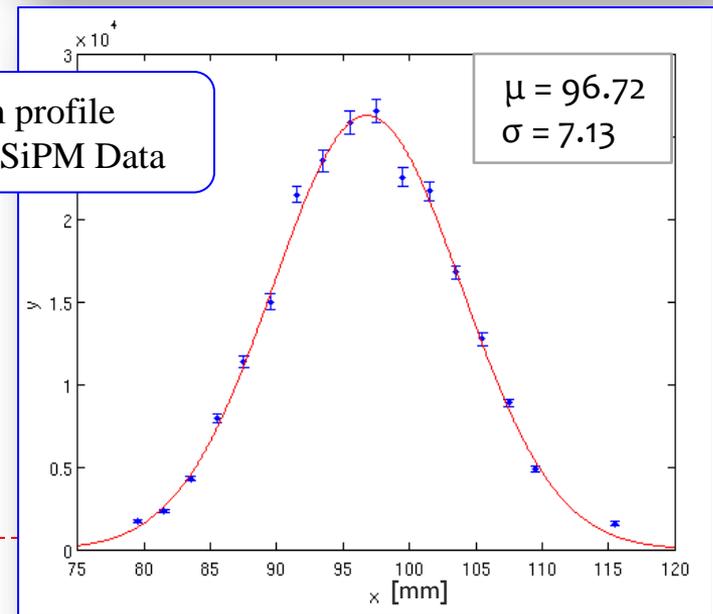
Type of event	Gamma Alarm	Neutron Alarm	Thermal Neutron Alarm	Message to the operator
Radioactive Source	YES	NO	NO	Type of source (within the implemented library)
NORM	YES	NO	NO	Type of NORM (within the implemented library)
Heavy lead shielded neutron source	NO	YES	NO	Lead shielded neutron source
Poly shielded Neutron source	YES	NO	YES	Poly shielded neutron source
Poly and lead shielded Neutron source	NO	NO	YES	Poly-Lead shielded neutron source
²⁵² Cf source	YES	YES	NO	²⁵² Cf source
Am/Be or Pu/Be source	YES	YES	NO	(alpha,n) neutron source
Pu source	YES	YES	NO	Pu source
U source	YES	NO	NO	U source

Saturation check

Beam profile from film image



Beam profile from SiPM Data



$$F = \frac{Y_{\text{Integration}}(x=x_i)}{Y_{\text{image}}(x=x_i)}$$

